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Power Matters.™

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JAN2N706

Overview

Diagrams

Electrical Rating	Symbol	Min	Typ	Max	Unit
DC Current Gain	HFE	30.00		120.00	

Maximum Electrical Rating	Symbol	Min	Typ	Max	Unit
Collector Current (dc)	I_C			0.01	A
Collector-Emitter Voltage (Base Open)	V_{CEO}			15.00	V
Junction Temperature (°C)	T_J			20.00	°C

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